Dielectric tunability properties of the  $Pb(Mg_{1/3}Nb_{2/3})_{0.8}(Sc_{1/2}Nb_{1/2})_{0.2}O_3$  ceramics

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## **Abstract**

Pure perovskite Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)<sub>0.8</sub>(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)<sub>0.2</sub>O<sub>3</sub> ceramics was prepared via a modified "columbite-type" method. The 1:1 B-site ordered structure of Pb(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)O<sub>3</sub> was detected by XRD and TEM. The dielectric relaxor behavior was described by a Lorentz relation. The dielectric tunability properties were investigated at 300K and 10 kHz. The results show that the ceramics possesses high dielectric tunability (~ 75% at 30 kV/cm), low dielectric loss (~ 0.003) and high figure of merit (~ 250), indicating that it is a promising tunable material. The high dielectric nonlinear behavior was illustrated by employing the Landau-Ginsberg-Devonshire thermodynamic theory and a multipolarization mechanism model. The results indicate that the high non-linearity is related to the contributions of the "extrinsic" polarizations such as the polar nanoregions and nanometer domain wall motions, etc., in addition to the contribution of the "intrinsic" lattice phonon polarization.

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#### 1. Introduction

Recently, there has been considerable interest in electric field tunable dielectric materials due to their potential applications as phase shifters, filters, and wireless communications[1-3]. These applications demand dielectric materials possessing high dielectric tunability, low dielectric loss and thermal stability [4,5], etc. However, it was found that the high dielectric tunability and low dielectric loss are two conflicting parameters; high dielectric tunability generally leads to high dielectric loss. Usually, an effective way to get the best compromise between the two is to dope oxides that have low dielectric losses, such as MgO, ZrO<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub>, TiO<sub>2</sub> and MgAl<sub>2</sub>O<sub>4</sub>[6-10], etc., into the dielectric materials. To attain these requirements, most research efforts in this field are focused on investigating normal ferroelectrics (Ba,Sr)TiO<sub>3</sub>, (Ba,Sn)TiO<sub>3</sub>, and (Sr,Pb)TiO<sub>3</sub> system[], etc. Other possible candidates for such applications are relaxor ferroelectrics, such as Ba(Zr,Ti)O<sub>3</sub>, Ba(Ti,Ga,Nb)O<sub>3</sub>, (Pb,Ba,La)(Zr,Sn,Ti)O<sub>3</sub> and PMN[], etc, which are characterized by a broad and frequency-dependent relative permittivity maximum ( $\varepsilon_{r,max}$ )[].

The Pb(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)O<sub>3</sub> (PSN) ceramics exhibits normal ferroelectric behavior due to the formation of a complete 1:1 B-site ordered structure, in which one cation position occupied by scandium and the other by niobium[]. In contrast, the Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)O<sub>3</sub> (PMN) ceramics exhibits prototypical relaxor ferroelectric behavior. The difference is attributed to the absence of complete chemical order in the 1:1 random site of the PMN systems[]. One interesting thing is that complete 1:1 B-site ordering can be induced in the PMN relaxor ferroelectric by a small amount of B-site

additives such as Sc, etc[]. As a result, in the Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)<sub>1-x</sub>(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)<sub>x</sub>O<sub>3</sub> (PSMN) systems, a crossover from relaxor to normal ferroelectric behavior can be observed close to x = 0.5. However, up to now, to our knowledge, literatures concerning the tunable dielectric properties of the PSMN ceramics are rare. Therefore, it is quite necessary to carry out the investigations on the aforementioned topics.

In this work, we report the dielectric tunability properties of the  $Pb(Mg_{1/3}Nb_{2/3})_{0.8}(Sc_{1/2}Nb_{1/2})_{0.2}O_3$  (PSMN20) ceramics possessing B-site cation 1:1 partially-ordering at room temperature. It is found that high dielectric tunability, low dielectric loss and high figure of merit can be achieved in this composition.

## 2. Experimental procedure

The PSMN20 ceramics were synthesized using high-purity (99.9%) oxides via a modified "columbite-type" route[]. Firstly, analytical grade powders of the B-site oxides were pre-reacted at 1100 °C for 6 h in air, and then the pre-reacted powders were mixed with stoichiometric amounts of lead oxide powders, milled for 6 h and calcined at 900 °C for 4 h to form perovskite phase. Pressed pellets, with 10 mm in diameter by 1 mm thick, were formed by cold-isostatic pressing at 300 MPa. The preformed pellets were sintered at 1240 °C for 2 h in air and then cooled naturally to room temperature. Sintering was carried out inside a covered alumina crucible, and the pellets were covered with powder of the same composition to minimize the lead loss during firing.

The density of all the pellets was measured by the Archimedes method. The crystal structures of the sintered pellets were analyzed using X-ray diffraction (XRD;

D/Max2550VB+/PC, Rigaku, Tokyo, Japan) with Cu  $K_{\alpha}$  radiation ( $\lambda$  = 0.15406 nm) over 20 in the range of 10°-90°. The crystal phases were compared with the powder diffraction data from JCPDS-ICDD (International Center of Diffraction Data). The microstructure of the ceramics was characterized using field emission transmission electron microscope (TEM; Tecnai F30G<sup>2</sup>, FEI, America) operated at 300 kV.

Low-field dielectric responses at a signal level of 500 mV/mm were measured by using a precision impedance analyzer (4294A, Agilent, USA) associated with a temperature controller (TP94, Linkam, UK) over a temperature range of 173–673 K at a heating rate of 3 °C/min. The dc electric field dependence of the dielectric permittivity was measured at 10 kHz and 300 K.

#### 3. Results and discussions

Density measurement indicates that the PSMN20 ceramics has relative density 98%. X-ray diffraction (XRD) pattern (Fig. 1) indicates that single perovskite phase composition with a cubic symmetry (unit cell parameter a=4.082 Å) was formed. Weak superlattice diffractions were detected, indicating the formation of a 1:1 B-site ordered structure []. The appearance of ordered domains (see the inset in Fig. 1) in the TEM centered dark-field image (CDF) formed with the  $\left(\frac{1}{2}\frac{1}{2}\frac{1}{2}\right)$  superlattice spot in the <110> zone axis electron diffraction pattern, further confirms the existence of 1:1 B-site ordered structure. Obviously, it is a partial 1:1 B-site ordered structure for PSMN20. In addition, the sharp electron diffraction spots with no satellites also further confirm the existence of single perovskite phase.

The dependence of the real part  $(\varepsilon')$  and imaginary part  $(\varepsilon'')$  of dielectric

permittivity vs. temperature at 100 Hz, 1 kHz and 10 kHz is shown in Fig. 2. The dielectric properties show high values of the real part of permittivity at room temperature and 10 kHz (~10,000) and at  $T_{\rm m}$  (~12,000); and low imaginary part:  $\varepsilon$ \* < 0.03 in the range (300–600)K and below 0.5 at  $T_{\rm m}$ . The PSMN20 ceramics exhibits typical relaxor character, namely the decrease of  $T_{\rm m}$  at the maximum  $\varepsilon$ '(T) with the increase of frequency and the strong dielectric dispersion at temperatures around and below  $T_{\rm m}$ , or the increase of  $T_{\rm m}$ " at the maximum  $\varepsilon$ \*(T) maximum with the increase of frequency and the strong dielectric dispersion at temperatures around and up  $T_{\rm m}$ \*[]. The relaxor behavior is considered to be closely related to the response of polar nanoregions (PNRs), which are described as nanosized polar islands embedded in an average cubic matrix[].

In order to describe the dielectric relaxor behavior at  $T > T_{\rm m}$ , several relations have been proposed, one of which is the Lorentz-type empirical relation[],

$$\varepsilon_A/\varepsilon' = 1 + (T - T_A)^2 / 2\delta_A^2 \tag{1}$$

Where  $T_A$  ( $T_A \neq T_{\rm m}$ ) and  $\varepsilon_A$  are the parameters defining the temperature of the dielectric peak and the extrapolated value of  $\varepsilon'$  at  $T=T_A$ , respectively. The parameter  $\delta_A$  is temperature and frequency independent, reflecting the diffuseness of the dielectric peak. The greater the relaxor dispersion is, the bigger  $\delta_A$  is. It is found that the above relation can describe the high temperature ( $T>T_{\rm m}$ ) dielectric permittivity quite well in a number of relaxor ferroelectrics[], as well as the normal ferroelectrics such as the BaTiO<sub>3</sub>[], etc.. Likewise, at  $T>T_{\rm m}$ , the  $\varepsilon'(T)$  of PSMN20 ceramics can well be fitted by the Lorentz relation (see the red solid line in Fig. 2). Table I lists the

best Lorentz fitting parameters for PSMN20, Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)O<sub>3</sub>, Ba(Zr<sub>0.25</sub>Ti<sub>0.75</sub>)O<sub>3</sub> and BaTiO<sub>3</sub>[]. The Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)O<sub>3</sub>, Ba(Zr<sub>0.25</sub>Ti<sub>0.75</sub>)O<sub>3</sub> and BaTiO<sub>3</sub> are the classical relaxors, quasi-ferroelectric and normal ferroelectrics[], respectively. The  $\delta_A$  for PSMN20, Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)O<sub>3</sub>, Ba(Zr<sub>0.25</sub>Ti<sub>0.75</sub>)O<sub>3</sub> and BaTiO<sub>3</sub> is 77.35, 103.6, 72 and 37, respectively. It can be seen that the  $\delta_A$  (77.35) for PSMN20 is close to that (72) for Ba(Zr<sub>0.25</sub>Ti<sub>0.75</sub>)O<sub>3</sub>. Therefore, it is suggested that a decrease in the degree of relaxor dispersion or an increase in the degree of the order is attained for PSMN20. The result is consistent with that observed in the inset of Fig.1.

Fig. 3 illustrates the temperature dependence of the dielectric loss ( $\tan\delta$ ) of the PSMN20 ceramics at 100 Hz, 1 kHz and 10 kHz. The dielectric loss of the PSMN20 ceramics at 100 Hz, 1 kHz and 10 kHz at 300 K is 0.0025, 0.0027 and 0.003, respectively. Further, low dielectric losses (< 0.005) in a wide temperature (300-400 K) are observed. These results show that the thermal and frequency stabilities, which are important parameters for tunable application, are excellent for PSMN20.

In addition, as shown by the arrow in Fig. 3, there is a low-frequency dielectric relaxation in the higher temperature range (> 475 K). It is reported that an increase in vacancies will lead to an increase in both the conductivity and the dielectric relaxation, as a result, a correlation between the dielectric relaxation and the dc conductivity ( $\sigma_{dc}$ ) was established[]. The inset in Fig. 3 shows the  $ln(\sigma_{dc})$  versus 1000/T, the plot is found to be linear and fitted using following Arrhenius equation:

$$\sigma_{dc} = \sigma_0 \exp\{-E_{dc}/(k_B T)\}\tag{2}$$

Where  $\sigma_0$  is the pre-exponential factor,  $E_{dc}$  is the activation energy for the dc

conduction,  $k_{\rm B}$  the Boltzmann constant, and T the absolute temperature. The calculated activation energy was 1.22 eV, which is in good agreement with the activation energy (1.07–1.31 eV) obtained for oxygen vacancies in the perovskite materials[]. Hence, it is reasonable to assume that the localized oxygen vacancies act as "polarons"[], leading to a low frequency dielectric relaxation in the higher temperature range of the dielectric loss.

Fig. 4 shows the dependence of the dielectric permittivity  $\varepsilon'$  and the dielectric loss  $\tan\delta$  vs. dc bias electric field at 10 kHz and 300 K. It can be seen that the dielectric permittivity  $\varepsilon'$  decreases sharply with the increase of the electric field, indicating that there is a high dielectric nonlinear electric field dependence, whilst the dielectric loss decreases slightly with the increase of the electric field. The dielectric tunability  $(\eta_r)$  was defined as:

$$\eta_r(\%) = \frac{(\varepsilon'(0) - \varepsilon'(E))}{\varepsilon'(0)} \times 100$$

(3)

where  $\varepsilon'(0)$  and  $\varepsilon'(E)$  represent the real part of the dielectric permittivity at zero and applied electric field, respectively. It was found that the dielectric tunability increases with the increase of the electric field and the large value of 75% is obtained at E=30 kV/cm. Nonetheless, the competence of a dielectric for tunable applications requires not only high value of dielectric tunability but also low dielectric loss. Figure-of-merit (*FOM*) of dielectric tunable properties is defined as:

$$FOM = \frac{\eta_r(\%)}{\tan \delta_0} \tag{4}$$

where  $\tan \delta_0$  is the dielectric loss without dc bias. Similar to the dielectric tunability, FOM obtained in the PSMN20 ceramics also increases with the increase of the electric field and a maximum value of 250 appears at E=30 kV/cm. For comparison, Table II lists the FOMs for the PSMN20,  $Ba_{0.4}Sr_{0.6}TiO3$ ,  $BaZr_{0.30}Ti_{0.70}O_3$  and  $Pb_{0.35}Sr_{0.65}TiO_3$  ceramics respectively[], as well as the  $\eta_r$  and  $\tan \delta$ . The FOMs obtained for PSMN20,  $Ba_{0.4}Sr_{0.6}TiO_3$ ,  $BaZr_{0.30}Ti_{0.70}O_3$  and  $Pb_{0.35}Sr_{0.65}TiO_3$  are 250 (30 kV/cm), 200 (30 kV/cm), 225 (40 kV/cm) and 60 (40 kV/cm), respectively, at 10 kHz and 300 K. Obviously, the PSMN20 ceramic has the biggest FOM, indicating that it is an attractive material for tunable applications. Furthermore, the higher FOMs for this composition may be obtained by further decreasing the dielectric loss through the addition of additives[].

In the case of a single lattice phonon polarization mechanism dominantly existing in polar dielectrics such as KTaO<sub>3</sub> and (Sr,Ba)TiO<sub>3</sub>[], etc., it is found that the Landau-Ginzburg-Devonshire (LGD) thermodynamic theory works well when describing the  $\varepsilon'(E)$ . Similarly, in this work, the LGD thermodynamic theory is employed to analyze the  $\varepsilon'(E)$  of PSMN20.

$$\varepsilon'(E) = \varepsilon'(0)/\{1 + \lambda[\varepsilon_0 \varepsilon'(0)^3 E^2]\}^{1/3}$$
(5)

where  $\varepsilon_0$  is the permittivity of free space,  $\lambda$  is a temperature-independent coefficient. The blue short dot line in Fig.4 shows the fitting of the Eq. (5) to the  $\varepsilon'(E)$  of PSMN20 at 10 kHz and 300 K. Obviously, LGD is invalid for describing the  $\varepsilon'(E)$ . It has been known that, for relaxor ferroelectrics, in addition to the "intrinsic" contribution such as electron and phonon, the "extrinsic" contribution such as the nanopolar clusters (or

polar nanoregions), domain wall motions and domain boundary polarization may become important at low frequencies[]. Therefore, it is not hard to understand the unavailability for the LGD describing the  $\varepsilon'(E)$  of PSMN20.

Taking into account of the contribution of the "intrinsic" and "extrinsic" polarizations to the  $\varepsilon'(E)$ , a multipolarization mechanism model is applied for the PSMN20 relaxor ferroelectric[].

$$\varepsilon(E) = \varepsilon_r(0) / \{1 + \lambda [\varepsilon_0 \varepsilon_r(0)^3 E^2]\}^{1/3} + (P_r x / \varepsilon_0) [\cosh(Ex)]^{-2}$$
(6)

where the first term represents the "intrinsic" polarization, the latter represents the "extrinsic" polarization contribution. The  $P_r$  is the effective polarization of one cluster, V the cluster size and  $k_B$  Boltzmann's constant and  $x = P_r V / (k_B T)$ . It can be seen that the experiment data is in good agreement with the multipolarization mechanism model (see the red solid line in Fig. 4). The result indicates that the high dielectric nonlinear behavior of the PSMN20 ceramics is related to the "extrinsic" polarization, in addition to the contribution of the "insinsic" lattice phonon polarization.

## 4. Conclusions

Pure perovskite Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)<sub>0.8</sub>(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)<sub>0.2</sub>O<sub>3</sub> relaxor ferroelectric ceramics can be synthesized using a modified "columbite-type" method. The partially-ordered 1: 1 B-site cation structure of was achieved. The high dielectric tunability (~ 75% at 30 kV/cm), low dielectric loss (~ 0.003) and high figure of merit (~ 250) were observed at 10 kHz and 300 K, making it become an attractive material for tunable device applications. The high dielectric nonlinear behavior is related to the contributions of the "extrinsic" polarizations such as the polar nanoregions and

nanometer domain wall motions, etc., in addition to the contribution of the "intrinsic" lattice phonon polarization.

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## References

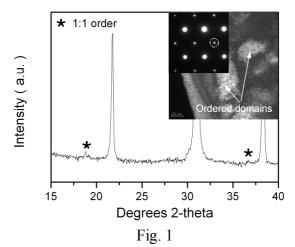
## **Captions**

Fig.1. XRD patterns of the Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)<sub>0.8</sub>(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)<sub>0.2</sub>O<sub>3</sub> ceramics. The inset is the TEM centered dark-field imaging with the  $\left(\frac{1}{2}\frac{1}{2}\frac{1}{2}\right)$  superlattice spot in the <110> zone axis electron diffraction pattern.

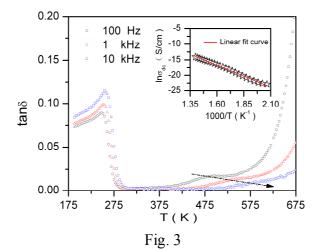
Fig.2. The temperature dependence of the real  $\varepsilon'$  and imaginary  $\varepsilon''$  parts of dielectric permittivity of the Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)<sub>0.8</sub>(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)<sub>0.2</sub>O<sub>3</sub> ceramics at 100 Hz, 1 kHz and 10 KHz. The red solid line is the Lorentz fit curve.

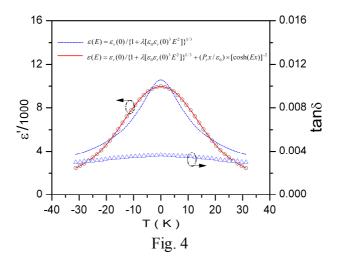
Fig.3. The temperature dependence of the dielectric loss ( $\tan \delta$ ) of the Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)<sub>0.8</sub>(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)<sub>0.2</sub>O<sub>3</sub> ceramics at 100 Hz, 1 kHz and 10 KHz. The inset is the temperature dependence of the dc conductivity ( $\sigma_{dc}$ ).

Fig.4. The dc electric field dependence of the dielectric permittivity  $\varepsilon'$  and loss  $\tan\delta$  of the Pb(Mg<sub>1/3</sub>Nb<sub>2/3</sub>)<sub>0.8</sub>(Sc<sub>1/2</sub>Nb<sub>1/2</sub>)<sub>0.2</sub>O<sub>3</sub> ceramics at 10 kHz and 300K. The red solid line is the  $\varepsilon(E) = \varepsilon_r(0)/\{1 + \lambda[\varepsilon_0\varepsilon_r(0)^3E^2]\}^{1/3} + (P_rx/\varepsilon_0) \times [\cosh(Ex)]^{-2}$  and the  $\varepsilon(E) = \varepsilon_r(0)/\{1 + \lambda[\varepsilon_0\varepsilon_r(0)^3E^2]\}^{1/3}$  fit curves, respectively.



15 3.0 100 Hz 1 kHz 10 kHz Lorentz fit 12 2.4 9 - 1.8 -ω <sub>6</sub> - 1.2 <sup>=</sup> ω 3 - 0.6 0 -1 575 375 475 T(K) 175 275 Fig. 2





 $\label{eq:control_state} \begin{array}{llll} Table & I. & Lorentz & fit & results & for & Pb(Mg_{1/3}Nb_{2/3})_{0.8}(Sc_{1/2}Nb_{1/2})_{0.2}O_3, & Pb(Mg_{1/3}Nb_{2/3})O_3, \\ Ba(Zr_{0.25}Ti_{0.75})O_3 & and & BaTiO_3. \\ \end{array}$ 

Sample	f	$T_{ m m}$	$\varepsilon_{ m m}$	$T_{\mathrm{A}}$	$arepsilon_{ m A}$	$\delta_{ m A}$
	(kHz)	(K)		(K)		(K)
Pb(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub>	10	267.7	10986	250.6	11954	103.6
$Pb(Mg_{1/3}Nb_{2/3})_{0.8}(Sc_{1/2}Nb_{1/2})_{0.2}O_{3} \\$	10	281.15	11941	264. 28	12257	77. 35
$Ba(Zr_{0.25}Ti_{0.75})O_3$	10	232.5	6474	233.3	6364	72
BaTiO <sub>3</sub>	10	393	23371	358	61670	37

Table II. Dilectric tunabilities  $(\eta_r)$ , dielectric losses  $(\tan\delta)$  and figures of merit (FOM) for the  $Pb(Mg_{1/3}Nb_{2/3})_{0.8}(Sc_{1/2}Nb_{1/2})_{0.2}O_3$ ,  $Ba_{0.4}Sr_{0.6}TiO3$ ,  $BaZr_{0.30}Ti_{0.70}O_3$  and  $Pb_{0.35}Sr_{0.65}TiO_3$  at 300 K.

Sample	F	Е	$\eta_r$	tanδ	FOM
	(kHz)	(kV/cm)			
$Pb(Mg_{1/3}Nb_{2/3})_{0.8}(Sc_{1/2}Nb_{1/2})_{0.2}O_{3}$	10	30	75%	0.003	250
$Ba_{0.4}Sr_{0.6}TiO_3$	10	30	12%	0.0006	200
$BaZr_{0.30}Ti_{0.70}O_{3}$	10	40	45%	0.002	225
$Pb_{0.35}Sr_{0.65}TiO_3$	10	40	48%	0.008	60

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# Dielectric and tunability properties of the Pb(Mg1/3Nb2/3)1-xZrxO3 ceramics

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